NSN 5961-01-213-4389

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-213-4389

Inclosure Material:
Metal
Overall Length:
0.085 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 40.0 collector to emitter
voltage, dc with base short-circuited to emitter and 6.0 emitter to base voltage, dc
Current Rating Per Characteristic:
0.50 amperes source cutoff current
Power Rating Per Characteristic:
2.0 watts small-signal input power, common-collector preset
Transfer Ratio:
300.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Lead finish gold
Precious Material:
Gold
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

No

NSN 5961-01-213-4389 Transistor - Page 2 of 2



Fiig:

A110a0